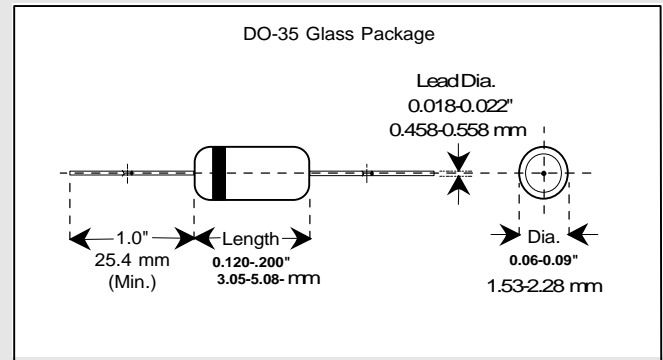


## Applications

Used in general purpose applications, where a controlled forward characteristic and fast switching speed are important.

## Features

- Six sigma quality
- Metallurgically bonded
- BKC's Sigma Bond™ plating for problem free solderability



Maximum Ratings		Symbol	Value	Unit
Peak Inverse Voltage		PIV	85 (Min).	Volts
Average Rectified Current		Iavg	200	mAmps
Continuous Forward Current		I <sub>Fdc</sub>	500	mAmps
Peak Surge Current (t <sub>peak</sub> = 1 sec.)		I <sub>peak</sub>	1.0	Amp
BKC Power Dissipation T <sub>L</sub> =50 °C, L = 3/8" from body		P <sub>tot</sub>	500	mWatts
Operating Temperature Range		T <sub>Op</sub>	-65 to +150	° C
Storage Temperature Range		T <sub>St</sub>	-65 to +150	° C
Electrical Characteristics @ 25 °C*	Symbol	Minimum	Maximum	Unit
Forward Voltage Drop @ I <sub>F</sub> = 400 mA	V <sub>F</sub>	***	1.10	Volts
Breakdown Voltage @ I <sub>R</sub> = 25 µA	PIV	85		Volts
Reverse Leakage Current @ V <sub>R</sub> = 50 V	I <sub>R</sub>		100	µA
Reverse Recovery time (note 1)	t <sub>rr</sub>		10	nSecs

Note 1: Per Method 4031-A with  $I_F = 10$  mA,  $V_R = 6$  V,  $R_L = 100$  Ohms. \* UNLESS OTHERWISE SPECIFIED

# Silicon Switching Diode

LL4607

# L-35 Glass Package

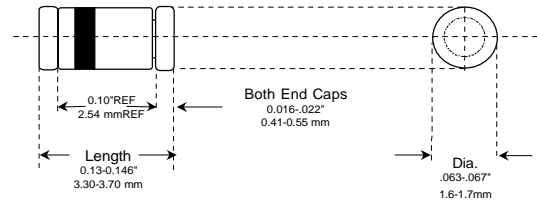
## Applications

Used in general purpose applications, where a controlled forward characteristic and fast switching speed are important.

## Features

- Six sigma quality
- Metallurgically bonded
- BKC's Sigma Bond™ plating for problem free solderability

### LL-34/35 MINI MELF Surface Mount Package DO-213AA



Maximum Ratings		Symbol	Value	Unit
Peak Inverse Voltage		PIV	85 (Min).	Volts
Average Rectified Current		I <sub>avg</sub>	200	mAmps
Continuous Forward Current		I <sub>Fdc</sub>	200	mAmps
Peak Surge Current (t <sub>peak</sub> = 1 sec.)		I <sub>peak</sub>	1.0	Amp
BKC Power Dissipation		P <sub>tot</sub>	500	mWatts
Operating Temperature Range		T <sub>Op</sub>	-65 to +200	° C
Storage Temperature Range		T <sub>St</sub>	-65 to +200	° C
Electrical Characteristics @ 25 °C*	Symbol	Minimum	Maximum	Unit
Forward Voltage Drop @ I <sub>F</sub> = 400 mA	V <sub>F</sub>	***	1.10	Volts
Breakdown Voltage @ I <sub>R</sub> = 25 µA	PIV	85		Volts
Reverse Leakage Current @ V <sub>R</sub> = 50 V	I <sub>R</sub>		100	µA
Reverse Recovery time (note 1)	t <sub>rr</sub>		10	nSecs

Note 1: Per Method 4031-A with I<sub>F</sub> = 10 mA, V<sub>R</sub> = 6 V, R<sub>L</sub> = 100 Ohms. \* UNLESS OTHERWISE SPECIFIED



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# Silicon Switching Diode

LL4608

# LL-35 Glass Package

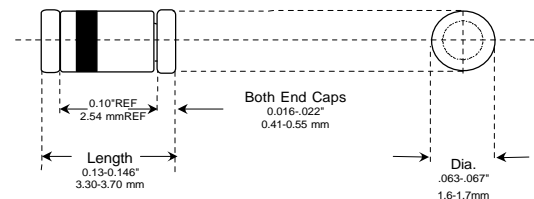
## Applications

Used in general purpose applications, where a controlled forward characteristic and fast switching speed are important.

## Features

- Six sigma quality
- Metallurgically bonded
- BKC's Sigma Bond™ plating for problem free solderability

### LL-34/35 MINI MELF Surface Mount Package DO-213AA



Maximum Ratings		Symbol	Value	Unit	
Peak Inverse Voltage		PIV	85 (Min).	Volts	
Average Rectified Current		Iavg	200	mAmps	
Continuous Forward Current		I <sub>Fdc</sub>	500	mAmps	
Peak Surge Current (t <sub>peak</sub> = 1 sec.)		I <sub>peak</sub>	1.0	Amp	
BKC Power Dissipation T <sub>L</sub> =50 °C, L = 3/8" from body		P <sub>tot</sub>	500	mWatts	
Operating Temperature Range		T <sub>Op</sub>	-65 to +150	° C	
Storage Temperature Range		T <sub>St</sub>	-65 to +150	° C	
Electrical Characteristics @ 25 °C*		Symbol	Minimum	Maximum	Unit
Forward Voltage Drop @ I <sub>F</sub> = 400 mA		V <sub>F</sub>	***	1.10	Volts
Breakdown Voltage @ I <sub>R</sub> = 25 µA		PIV	85		Volts
Reverse Leakage Current @ V <sub>R</sub> = 50 V		I <sub>R</sub>		100	µA
Reverse Recovery time (note 1)		t <sub>rr</sub>		10	nSecs

Note 1: Per Method 4031-A with I<sub>F</sub> = 10 mA, V<sub>R</sub> = 6 V, R<sub>L</sub> = 100 Ohms. \* UNLESS OTHERWISE SPECIFIED



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